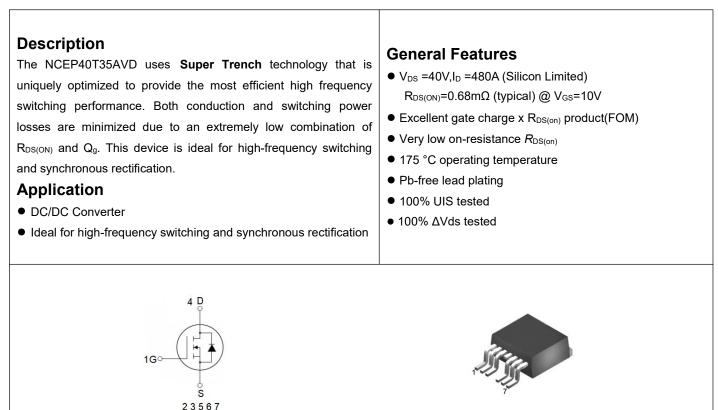


NCE N-Channel Super Trench Power MOSFET



TO-263-7L top view

Package Marking and Ordering Information

Schematic diagram

<u> </u>		<u> </u>			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP40T35AVD	NCEP40T35AVD	TO-263-7L	-	-	-

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous(Silicon Limited)(Note 1)	Ι _D	480	А
Drain Current-Continuous(Silicon Limited) ^(Note 1)	I _D (100℃)	343	A
Drain Current-Continuous(Package Limited)	I _D	350	A
Pulsed Drain Current	I _{DM}	1400	A
Maximum Power Dissipation	PD	380	W
Derating factor		2.53	W/℃
Single pulse avalanche energy (Note 2)	E _{AS}	3000	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{θJC}	0.39	°C/W	
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Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics	····					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	43	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics						•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10V, I_D =20A	-	0.68	0.88	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =20A	100	-	-	S
Dynamic Characteristics	· ·					
Input Capacitance	Clss		-	12850	-	pF
Output Capacitance	Coss	V _{DS} =20V,V _{GS} =0V, F=1.0MHz	-	4641	-	pF
Reverse Transfer Capacitance	Crss		-	205	-	pF
Switching Characteristics (Note 1)						
Turn-on Delay Time	t _{d(on)}		-	26	-	nS
Turn-on Rise Time	tr	V _{DD} =20V,I _D =20A	-	14	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	110	-	nS
Turn-Off Fall Time	t _f		-	17	-	nS
Total Gate Charge	Qg	N/ 00)// 00A	-	156.5	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =20V,I _D =20A, V _{GS} =10V	-	59	-	nC
Gate-Drain Charge	Q _{gd}		-	23.5	-	nC
Drain-Source Diode Characteristics	····					
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	ls		-	-	480	А
Reverse Recovery Time	trr	T_J = 25°C, I_F = I_S	-	66	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	240	-	nC

Notes:

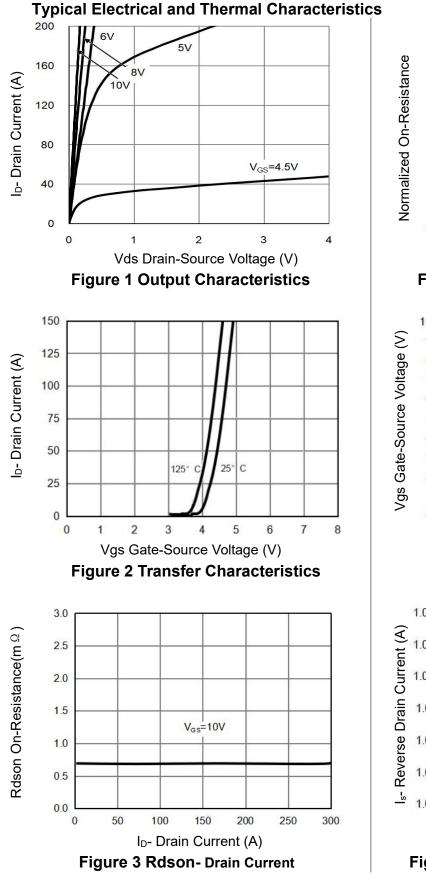
1. Defined by design.Not Subject to production test

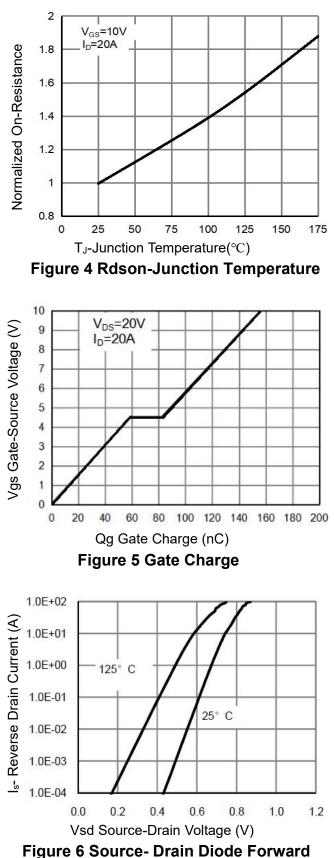
2. EAS condition : Tj=25 $^\circ\!\mathrm{C},V_{DD}$ =20V,V_G=10V,L=0.5mH,Rg=25 Ω

 These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



NCEP40T35AVD

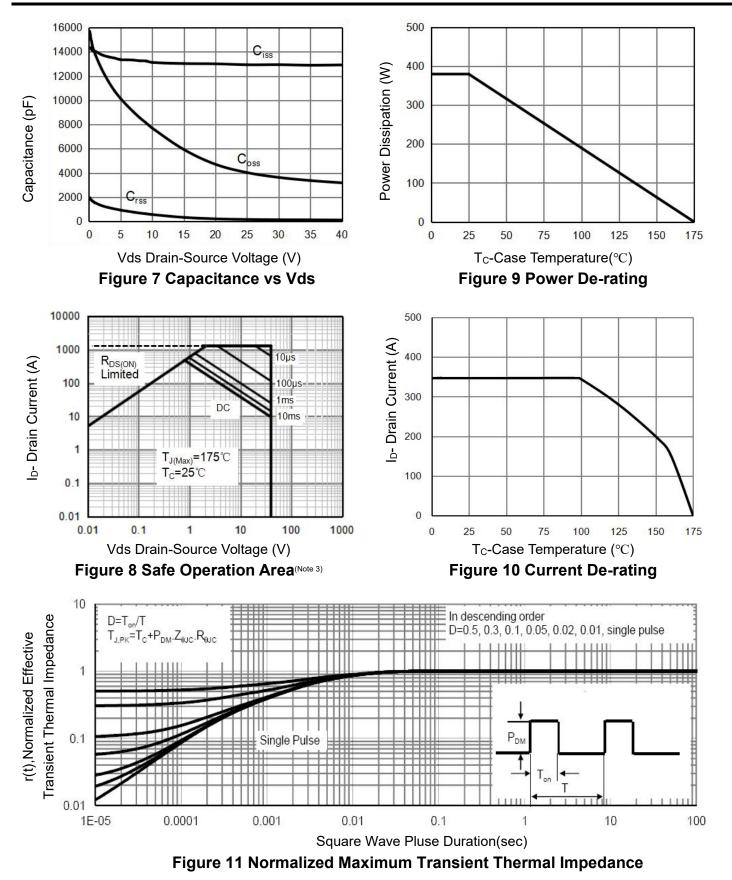






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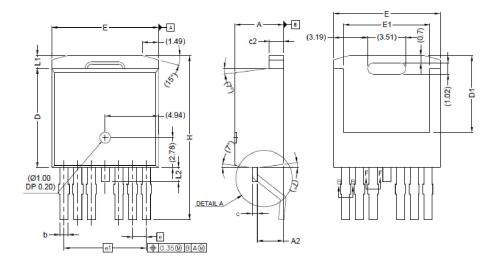
NCEP40T35AVD

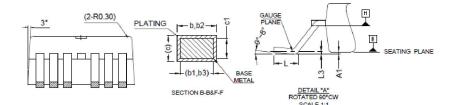




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TO-263-7L (B) Package Information



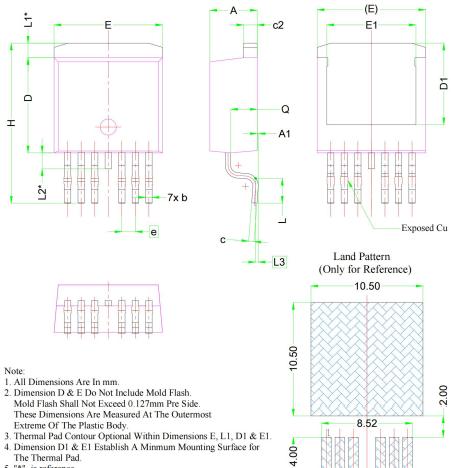


SYMBOL	MIN	MAX
A	4.30	4.70
A1	<u> </u>	0.25
A2	2.20	2.60
b	0.65	0.85
b1	0.65	0.80
b2	0.80	1.00
b3	0.80	0.95
С	0.45	0.60
c1	0.45	0.55
c2	1.25	1.40
D	9.00	9.40
D1	6.86	7.42
E	9.68	10.08
E1	7.70	8.30
e	1.2	7 BSC
e1	7.6	2 BSC
L	1.78	2.79
L1	-	1.60
L2	-	1.78
L3	0.2	5BSC
Н	14.61	15.88



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Package Information TO-263-7L (G)



- The Thermal Pad. 5. "*" is reference .

SYMBOL	DIMENSIONS			
	MIN.	NOM.	MAX.	
A	4.24	4.44	4.64	
A1	0.00	0.10	0.25	
b	0.50	0.60	0.70	
с	0.40	0.50	0.60	
c2	1.15	1.27	1.40	
D	8.82	8.92	9.02	
D1	6.86	7.65		
E	9.96	10.16	10.36	
E1	8.20	8.35	8.50	
е		1.27 BSC		
Н	14.61	15.00	15.88	
L	1.78	2.32	2.79	
L1	1.36 REF.			
L2	1.50 REF.			
L3	0.25 BSC			
Q	2.30	2.48	2.70	

0.90

1.27



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